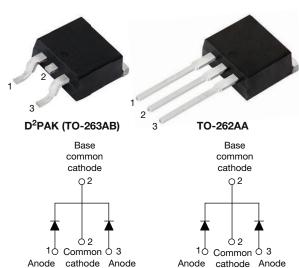


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RoHS COMPLIANT

High Performance Schottky Rectifier, 2 x 10 A

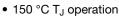


VS-MBRB20..CT-M3

VS-MBR20..CT-1-M3

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 10 A					
V _R	80 V, 90 V, 100 V					
V _F at I _F	0.70 V					
I _{RM} max.	6 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	7 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES



- · Low forward voltage drop
- · High frequency operation
- HALOGEN • Center tap D²PAK (TO-263 AB) and TO-262AA FREE packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform (per device)	20	٨				
I _{FRM}	T _C = 133 °C (per leg)	20	А				
V _{RRM}		80 to 100	V				
I _{FSM}	t _p = 5 μs sine	850	А				
V _F	10 A _{pk} , T _J = 125 °C	0.70	V				
TJ	Range	-65 to +150	°C				

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB2080CT-M3 VS-MBR2080CT-1-M3		VS-MBRB20100CT-M3 VS-MBR20100CT-1-M3	UNITS
Maximum DC reverse voltage	V _R	80	90	100	V
Maximum working peak reverse voltage	V _{RWM}	80	90	100	v

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average per leg	I	$T_{\rm C} = 133 ^{\circ}\text{C}$, rated $V_{\rm B}$	10				
forward current per device	I _{F(AV)}	$T_{\rm C} = 155$ °C, fated $v_{\rm R}$	20	1			
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C	20				
		5 µs sine or Following any rated load condition	850	Δ			
Non-repetitive peak surge current		3 µs rect. pulse and with rated V _{RRM} applied	000	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~			
Non repetitive peak surge current	I _{FSM}	Surge applied at rated load conditions halfwave,	150	A			
		single phase, 60 Hz					
Peak repetitive reverse surge current	I _{RRM}	2.0 μs, 1.0 kHz	0.5				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 12 mH	24	mJ			

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST C	VALUES	UNITS			
Maximum forward voltage drop		10 A	T _{.1} = 25 °C	0.80			
	V _{FM} ⁽¹⁾	20 A	$I_{\rm J} = 25$ C	0.95	v		
	VFM ("	10 A	T.I = 125 °C	0.70			
		20 A	IJ = 125 C	0.85			
Maximum instantaneous	I _{BM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.10	mA		
reverse current	IRM (''	T _J = 125 °C	hated DC voltage	6			
Threshold voltage	V _{F(TO)}			0.433	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		15.8	mΩ		
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rat	nge 100 kHz to 1 MHz), 25 °C	400	pF		
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

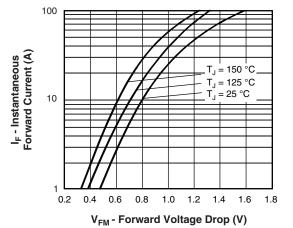
THERMAL - MECH	ANICAL	SPECIFIC	ATIONS			
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction temper	rature range	TJ		-65 to 150	°℃	
Maximum storage temper	ature range	T _{Stg}		-65 to 175	U	
Maximum thermal resistar junction to case per leg	nce,	R _{thJC}	DC operation	2.0		
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistar junction to ambient	ice,	R _{thJA}	DC operation	50		
Approvimate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm	
Mounting torque	maximum		Non-lubricated trireads	12 (10)	(lbf ⋅ in)	
			Case style D ² PAK (TO-263AB)	MBRB2 MBRB2 MBRB20	090CT	
Marking device			Case style TO-262AA	MBR208 MBR209 MBR201	90CT-1	

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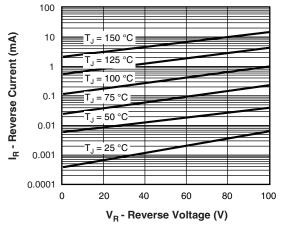


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

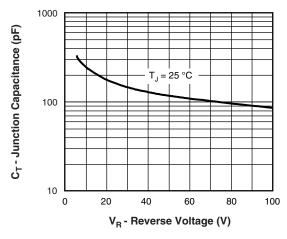
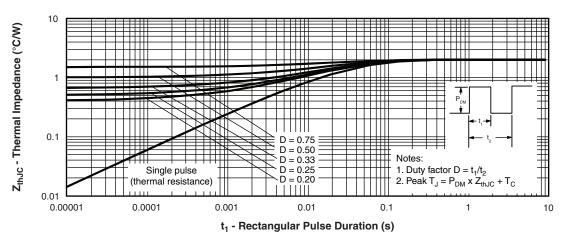
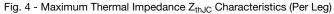


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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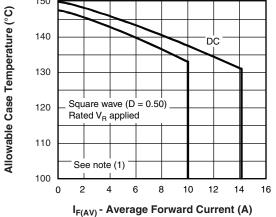
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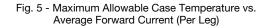
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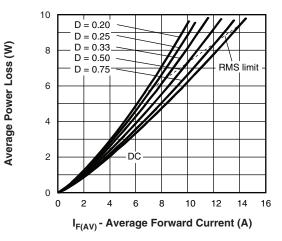
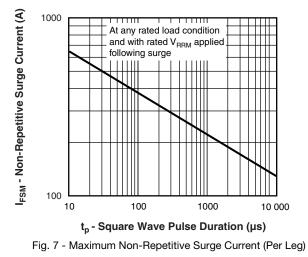


Fig. 6 - Forward Power Loss Characteristics (Per Leg)



Note

 $^{(1)}$ Formula used: $T_{C} = T_{J} - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_{R}$ (1 - D); I_{R} at V_{R1} = rated V_{R}

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ORDERING INFORMATION TABLE

Device code	vs-	MBR	В	20	100	СТ	-1	L	-M3
		2	3	4	5	6	7	8	9
	1	- Visł	nay Sen	nicondu	ctors pro	oduct			
	2	- Ess	ential pa	art numl	ber				
	3	• B	= D ² PA	K (TO-2	263AB)	7	None		
		• N	one = T	O-262A	A	7	= -1		
	4	- Cur	rent rati	ng (20 =	= 20 A)	80	= 80 V		
	5	- Voli	tage rati	ings —			= 90 V	,	
	6	- CT	= esser	ntial part	numbe	r [100	= 100 \	/	
	7	- • N	one = D	² PAK (1	FO-263A	AB) 3	= B		
		• -1	= TO-2	62AA		3	None		
	8	• N	one = tu	ıbe (50	pieces)				
		• L	= tape a	and reel	(left orie	ented - t	for D ² P/	AK (TO-	-263AB
	_	• R	= tape	and reel	(right o	riented	- for D ²	PAK (T	O-263A
	9	M3	3 = halo	gen-free	, RoHS	-complia	ant, and	l termina	ation lea

ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-MBRB20100CTL-M3	800	13" diameter plastic tape and reel					
VS-MBRB20100CT-M3	50	Antistatic plastic tubes					
VS-MBRB20100CTR-M3	800	13" diameter plastic tape and reel					
VS-MBRB2080CTL-M3	800	13" diameter plastic tape and reel					
VS-MBRB2080CT-M3	50	Antistatic plastic tubes					
VS-MBRB2080CTR-M3	800	13" diameter plastic tape and reel					
VS-MBRB2090CT-M3	50	Antistatic plastic tubes					
VS-MBR20100CT-1-M3	50	Antistatic plastic tubes					
VS-MBR2080CT-1-M3	50	Antistatic plastic tubes					
VS-MBR2090CT-1-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				

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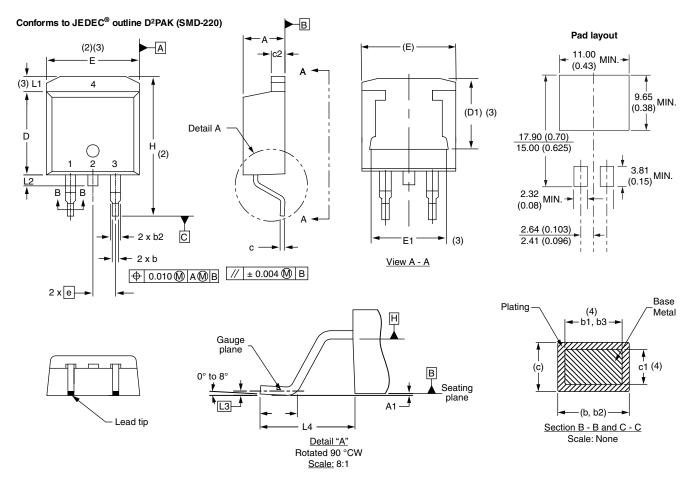


Outline Dimensions

Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	ETERS	INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES		
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	JIES STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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Document Number: 96164

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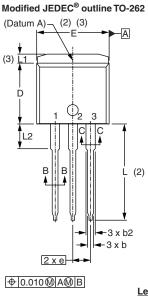


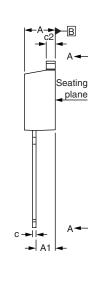
Outline Dimensions

Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches



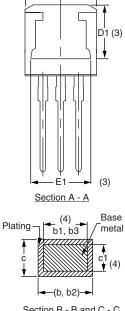


Lead assignments

Lead tip



1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode



F

Section B - B and C - C Scale: None

SYMBOL	MILLIN	IETERS	INC	NOTEO	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

 (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches Outline conform to JEDEC[®] TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), (6) L1 (max.), L2 (min., max.)

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